

Voltage-mode boost to ground evaluation kit

TLD5099EP

About this document

Product description

The TLD5099EP is an AEC qualified DC/DC boost controller.

- Built in diagnosis and protection features
- ENABLE control pin available
- Spread spectrum modulator to improve the EMI performance

Scope and purpose

Scope of this user manual is to provide to the audience instructions on usage of TLD5099EP voltage-mode boost to ground evaluation board.

Intended audience

This document is intended for engineers who need to perform measurements and check performances with TLD5099EP voltage-mode boost to ground evaluation board.

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2020-01-29

1 Description

1 Description

Evaluation board for medium power application with TLD5099EP configured in voltage-mode boost to ground topology. It can be implemented as a DC-DC power supply with constant voltage output.

Default configuration of the board is voltage-mode boost to ground topology without any additional features enabled. In this configuration, it can deliver up to 17 W to the load with an efficiency above 93%. Auxiliary circuits to protect the DC/DC and the load during short to ground, forcing the current to zero, are not present. The short to ground current is limited to few amps because of the SWCS pin connected to the current-mode shunt.

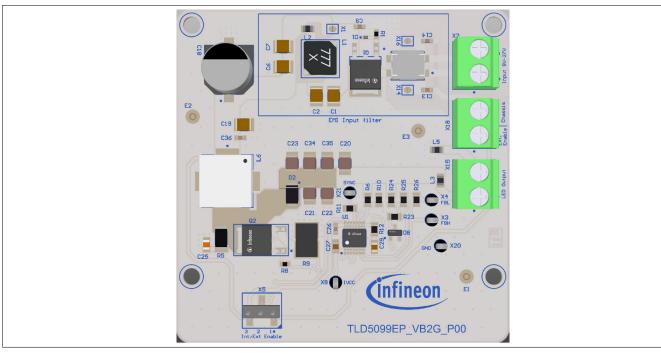


Figure 1 Board picture



1 Description

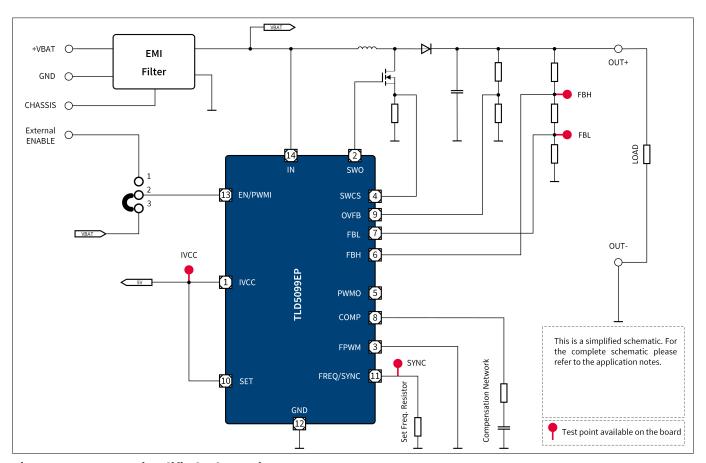


Figure 2 Simplified schematic

Table 1 Performance summary

Parameter	Conditions	Value
Input supply voltage	Parameter degradation below 6.5 V	8 V to 27 V
		Down to 6.5 V for less than 2 s
Maximum output current	Resistive load	350 mA
Switching frequency	V_{IN} = 13.2 V; spread spectrum "on"	400 kHz
Efficiency	Measured with a 139 Ω power resistor as load	> 93%
Output voltage range	Output voltage related to ground	48 V
Output overvoltage protection	Output voltage related to ground	60 V



2 Quick start procedure

2 Quick start procedure

The default configuration of the board has all additional features disabled. Jumper is positioned in 1-2 position. In this configuration ENABLE signal has to be applied on X18 (max 45 V). If another output voltage is required, the voltage divider composed of R24, R25, R26 must be changed according to the rule that a 300 mV dropout should be present across R25 when the desired voltage is present in the output.

The default configuration is depicted below:

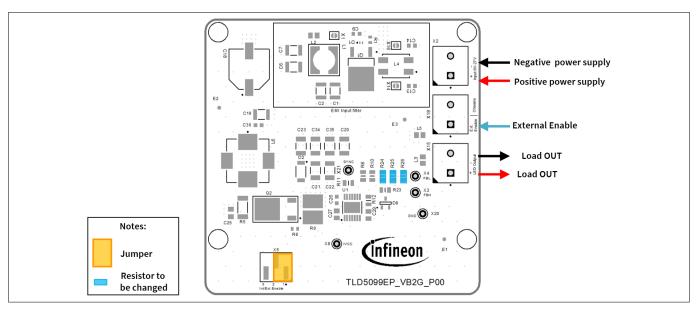


Figure 3 Default configuration of the board



3 Auto-enable configuration

3 Auto-enable configuration

By positioning the jumper on the position 2-3, an external enable signal to start the device is no longer needed.

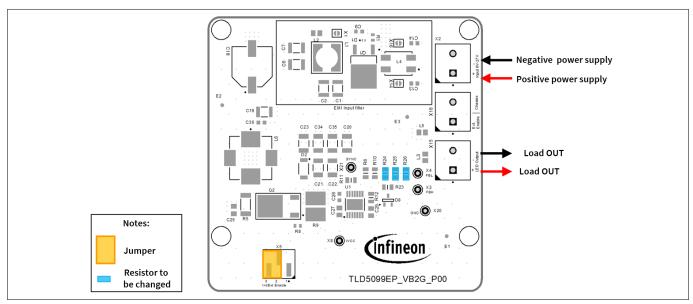


Figure 4 Auto-enable configuration



4 Schematics

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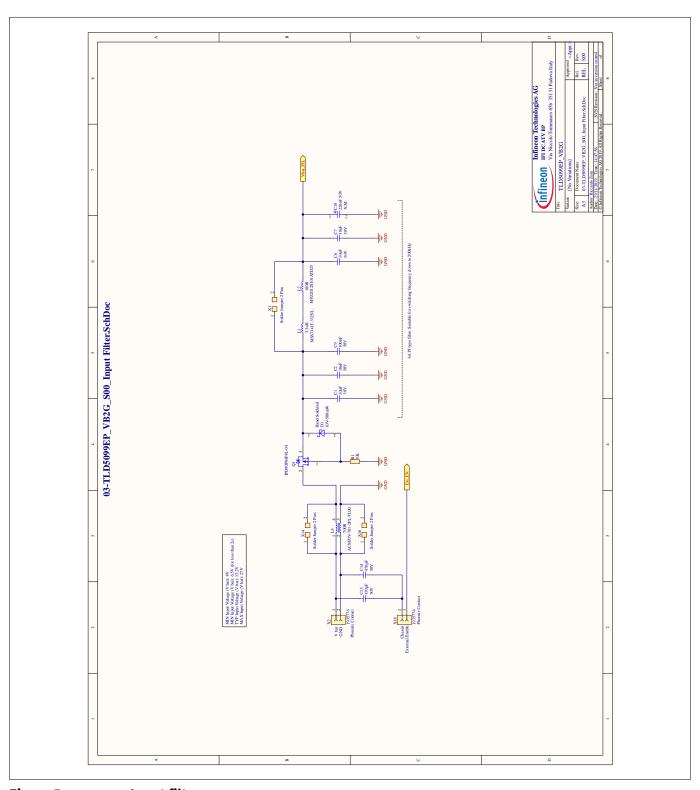
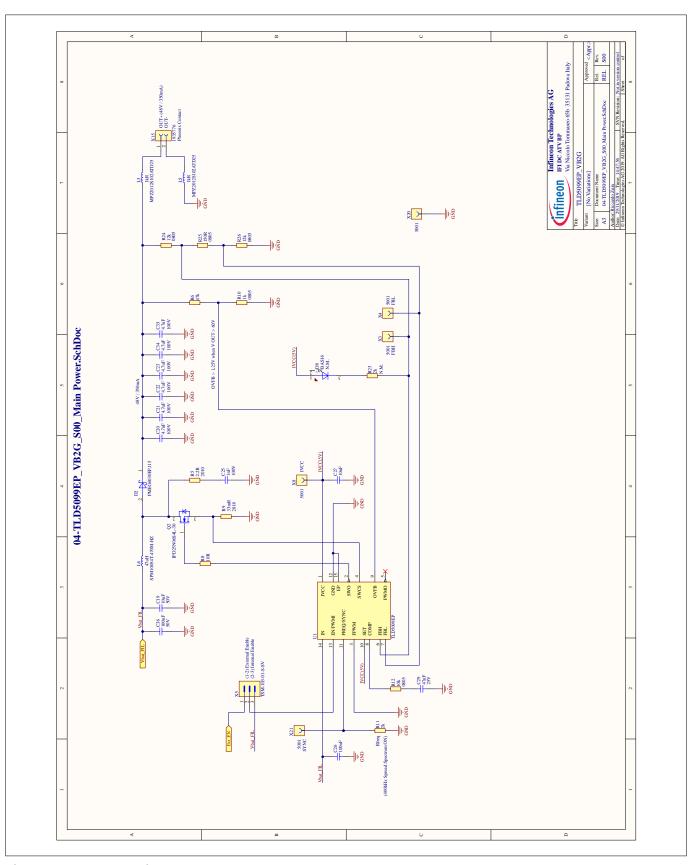


Figure 5 Input filter



4 Schematics



7

Figure 6 Main power



5 PCB layout

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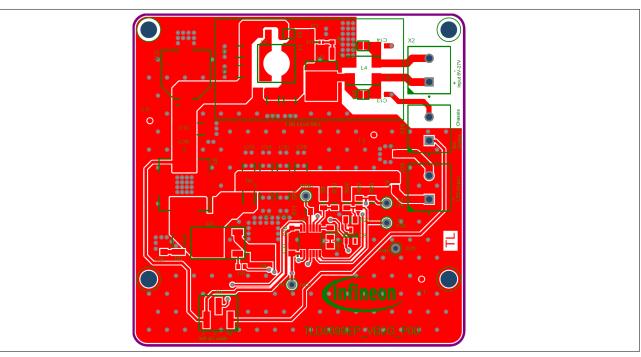


Figure 7 PCB layout top view

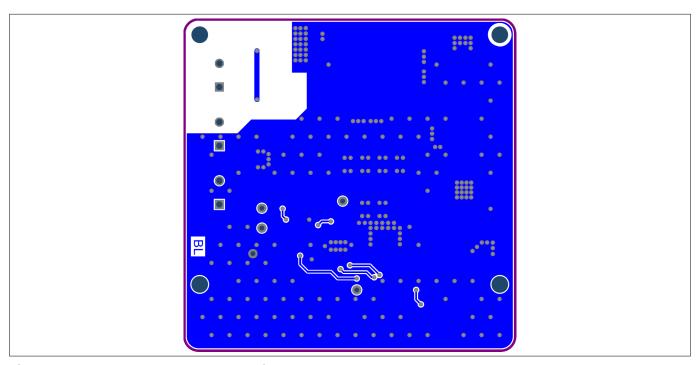


Figure 8 PCB layout bottom view



6 Bill of material

6 Bill of material

Table 2 Bill of material

Designator	Value	Manufacturer	Manufacturer order number
C1, C2, C6, C7, C19	10uF	muRata	GCM32EC71H106KA03
C9, C26, C36	100nF	AVX	06035C104K4Z2A
C13, C14	470pF	muRata	GCM1885C1H471JA16
C18	220uF	Panasonic	EEEFK1H221P
C20, C21, C22, C23, C34, C35	4.7uF	TDK	CGA6M3X7S2A475K200AE
C25	1nF	TDK Corporation	CGA4F2X7R2A102M085AE
C27	10uF	TDK	CGA4J1X7S1C106K125AC
C29	47nF	Kemet	C0805C473J3GACAUTO
D1	Zener 10V-500mW		
D2	PMEG6030EP,115	Nexperia	PMEG6030EP,115
D8	BAS16	Infineon Technologies	BAS16
L1	3.3uH	Coilcraft	MSS7341T-332NL
L2	100H	TDK Corporation	MPZ2012S101ATD25
L3, L5	1kH	TDK	MPZ2012S102ATD25
L4		TDK	ACM70V-701-2PL-TL00
L6	47uH	TDK	SPM10054T-470M-HZ
Q1	IPD90P04P4L-04	Infineon Technologies	IPD90P04P4L-04
Q2	IPD25N06S4L-30	Infineon Technologies	IPD25N06S4L-30
R1	10kΩ	Vishay	CRCW060310K0FK
R5	2.2Ω	Vishay	CRCW20102R20FK
R6	47kΩ	Vishay	CRCW080547K0FK
R8	10Ω	Vishay	CRCW060310R0FK
R9	33mΩ	Vishay	WSHM2818R0330FEA
R10	1kΩ	Vishay	CRCW08051K00FK
R11	2kΩ	Vishay	CRCW08052K00FK
R12	10kΩ	Vishay	CRCW080510K0FK
R23	2kΩ	Vishay	CRCW08052K00FK
R24, R26	12kΩ	Vishay	CRCW080512K0FK
R25	150Ω	Vishay	CRCW0805150RFK
U1	TLD5099EP	Infineon Technologies	TLD5099EP
X1, X14, X16	Solder Jumper 2 Pins	Infineon Technologies AG	Solder Jumper 2 Pins
X2, X15, X18	1935776	Phoenix Contact	1935776
X3, X4, X8, X20, X21	5001	Keystone	5001



6 Bill of material

Table 2 Bill of material (continued)

Designator	Value	Manufacturer	Manufacturer order number
X5	TSM-103-01-S-SV	Samtec	TSM-103-01-S-SV



7 Efficiency measurements

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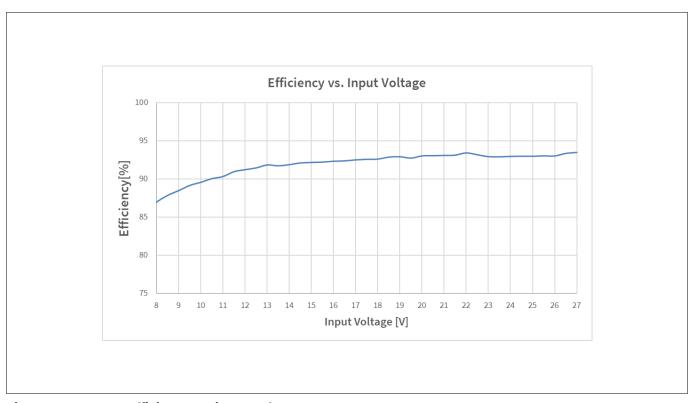


Figure 9 Efficiency vs. input voltage

This efficiency performance has been obtained with:

Table 3 Parameters influencing efficiency

Output load:	139 Ω power resistor
EMI filter:	Totally bypassed by closing the jumpers X1, X14 and X16

Efficiency performances can be increased: refer to *Chapter 8*.



8 Maximizing efficiency

8 Maximizing efficiency

This evaluation board has been designed to reach a fair compromise between efficiency performance and EMI emissions compliance.

Nevertheless, if the maximum efficiency is needed, the following actions are suggested:

- 1. Remove the snubber circuit R5, C25 or choose a lower value for the capacitor C25 (for example 470 pF)
- 2. Bypass the whole EMI filter by bridging the jumpers X1, X14 and X16
- **3.** Bypass the output ferrite beads L3 and L5
- **4.** Replace the main inductor L6 with one that boasts a lower parasitic DC resistance, for example
 - Vishay IHLP6767GZER470M8A
 - Bourns SRP1770TA-470M
- **5.** Bypass gate resistor R8



9 Minimizing EMI emissions

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This evaluation board has been designed to reach a fair compromise between efficiency performance and EMI emissions compliance. Furthermore, this evaluation board can fulfill the class V of the CISPR25 in conducted emissions from 150 kHz to 108 MHz.

Nevertheless, if the minimum EMI emission is required, the following actions should be considered:

- 1. Choose a higher value for the capacitor C25 (for example 2.2 nF)
- 2. Include the whole EMI filter by removing bridges from the jumpers X1, X14 and X16
- **3.** Replace the 10 Ω resistor R8 with a higher value such as 22 Ω or 33 Ω
- **4.** Replace the main inductor L6 with a shielded one (for example the Cyntec VCHE106G-470MS6) and connect the shield to ground
- **5.** With a short piece of wire connect the CHASSIS TERMINAL to the test ground plane as close as possible to where the board is placed



10 Revision history

10 Revision history

Document version	Date of release	Description of changes
Rev. 1.00	2020-01-29	First release related to evalboard S00_P00.

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